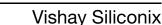
SPICE Device Model Si2367DS





P-Channel 20 V (D-S) MOSFET

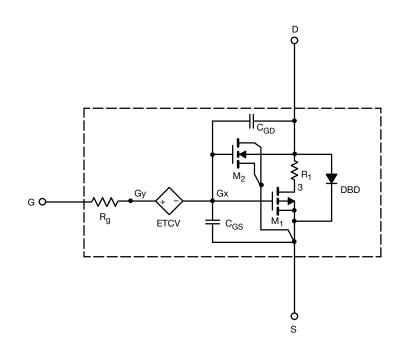
DESCRIPTION

The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The sub-circuit model is extracted and optimized over the -55 °C to +125 °C temperature ranges under the pulsed 0 V to 5 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{gd}\xspace$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Sub-circuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the -55 °C to +125 °C Temperature Range
- Model the Gate Charge



SUBCIRCUIT MODEL SCHEMATIC

Note

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.





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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	0.5	-	V
Drain-Source On-State Resistance ^a	R _{DS(on)}	V_{GS} = -4.5 V, I_D = -2.5 A	0.052	0.055	Ω
		V_{GS} = -2.5 V, I _D = -2 A	0.070	0.071	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -2.5 \text{ A}$	7.3	7.5	S
Diode Forward Voltage ^a	V _{SD}	I _S = -2 A	-0.76	-0.79	V
Dynamic ^b					
Input Capacitance	C _{iss}	V_{DS} = -10 V, V_{GS} = 0 V, f = 1 MHz	561	561	pF
Output Capacitance	Coss		112	112	
Reverse Transfer Capacitance	C _{rss}		89	89	
Total Gate Charge	Qg	$V_{DS} = -10 \text{ V}, \text{ V}_{GS} = -8 \text{ V}, \text{ I}_{D} = -2.5 \text{ A}$	12	15	nC
			7.4	9	
Gate-Source Charge	Q _{gs}	$V_{DS} = -10 \text{ V}, \text{ V}_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -2.5 \text{ A}$	1	1	
Gate-Drain Charge	Q _{gd}		2.5	2.5	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

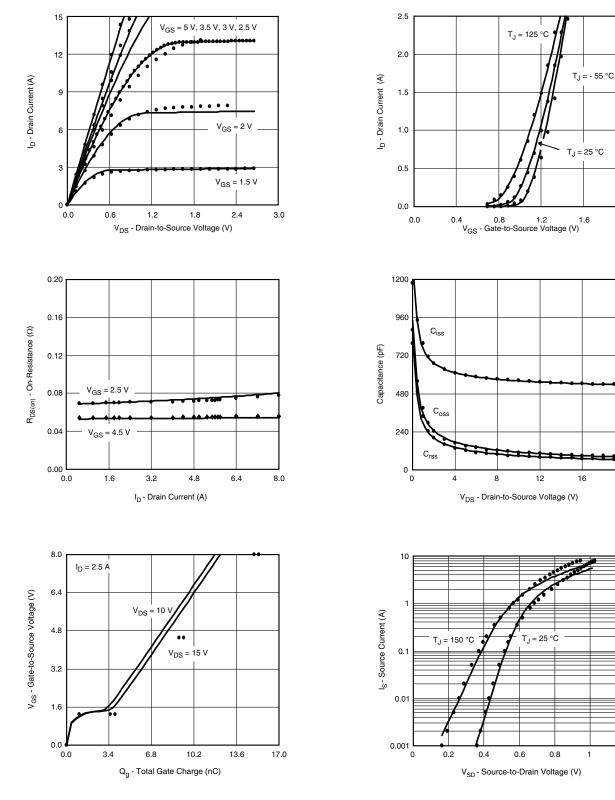


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COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)



Note

• Dots and squares represent measured data. Copyright: Vishay Intertechnology, Inc.

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3

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